



10G InGaAs PIN Photodiode TIA ROSA-LC Package

Description

A 10 Gb/s InGaAs PIN photodiode packaged with a transimpedance amplifier (TIA). This device is packaged in a TO-Can with LC flange receptacle. Offering flat response and a broad temperature operating range. The device allows a LC connector to be easily connected. The device is configured for vertical mounting on PCB. Flexible PCB can be soldered for horizontal mounting.

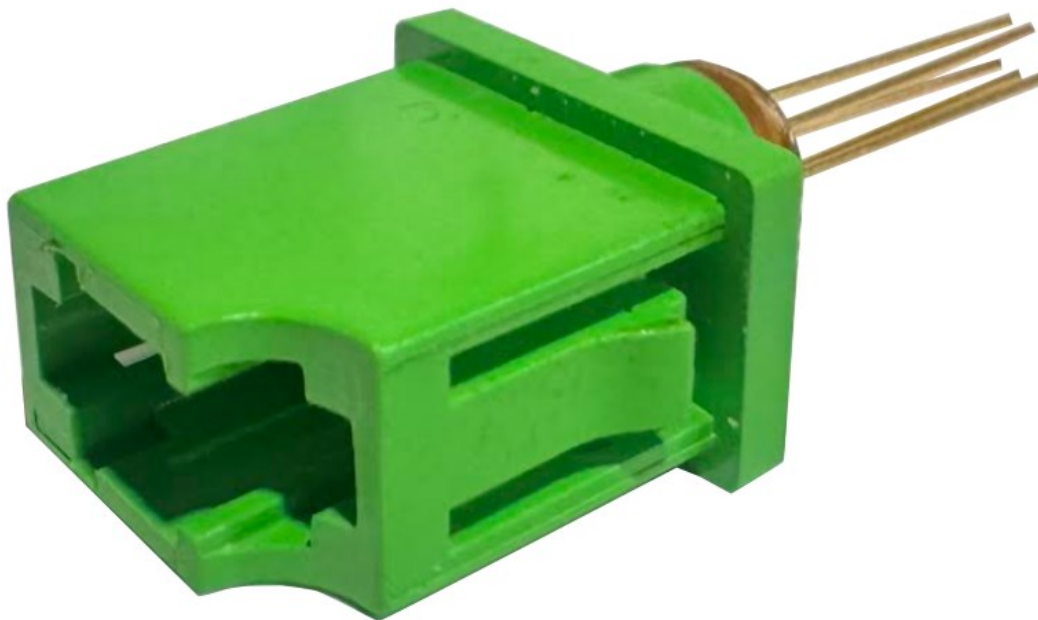
Features

- TO-Can Package
- LC Flange Receptacle
- 10 Gbps
- Wide temperature operating range
- Received signal strength indicator
- TIA Built in
- 4K Ohm Transimpedance Gain
- PCB solderable mount
- -17 dBm sensitivity



Applications

- 5G
- RF over Fiber (RFoF)



Photodiode Electro-Optical Characteristics ($T_{op} 23 \pm 3^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Supply Voltage	V_{cc}	2.9	3.3	3.6	V	
Supply Current	I_{cc}		26	35	mA	$V_{cc} = 3.3 \text{ V}$
Response Spectrum	λ	1260		1610	nm	$V_{cc} = 3.3 \text{ V}$
Bandwidth	BW		8		GHz	-3 dB bandwidth
Saturation	Sat		3		dBm	$V_{cc} = 3.3 \text{ V}$
Sensitivity	Sen		-17	-14	dBm	10.30 Gbps, 1310 nm, ER = 4.5 dB, BER = 10^{-12}
Optical Return Loss	ORL			-27	dB	CW = 1310 nm
RSSI Offset Current	I_{RSS}			100	nA	$V_{cc} = 3.3 \text{ V}$
Responsivity	R	0.7	0.8		A/W	1310 nm, 50 % VBR, M=2, Pin -20 dBm
Dark Current	I_d		1	5	nA	VBr
Output Impedance	Z_o		100			Differential
Maximum Output Voltage	V_o		300		mV _{p-p}	Differential
Low Frequency Cutoff	F_{low}		10		KHz	

Photodiode Absolute Maximum Ratings

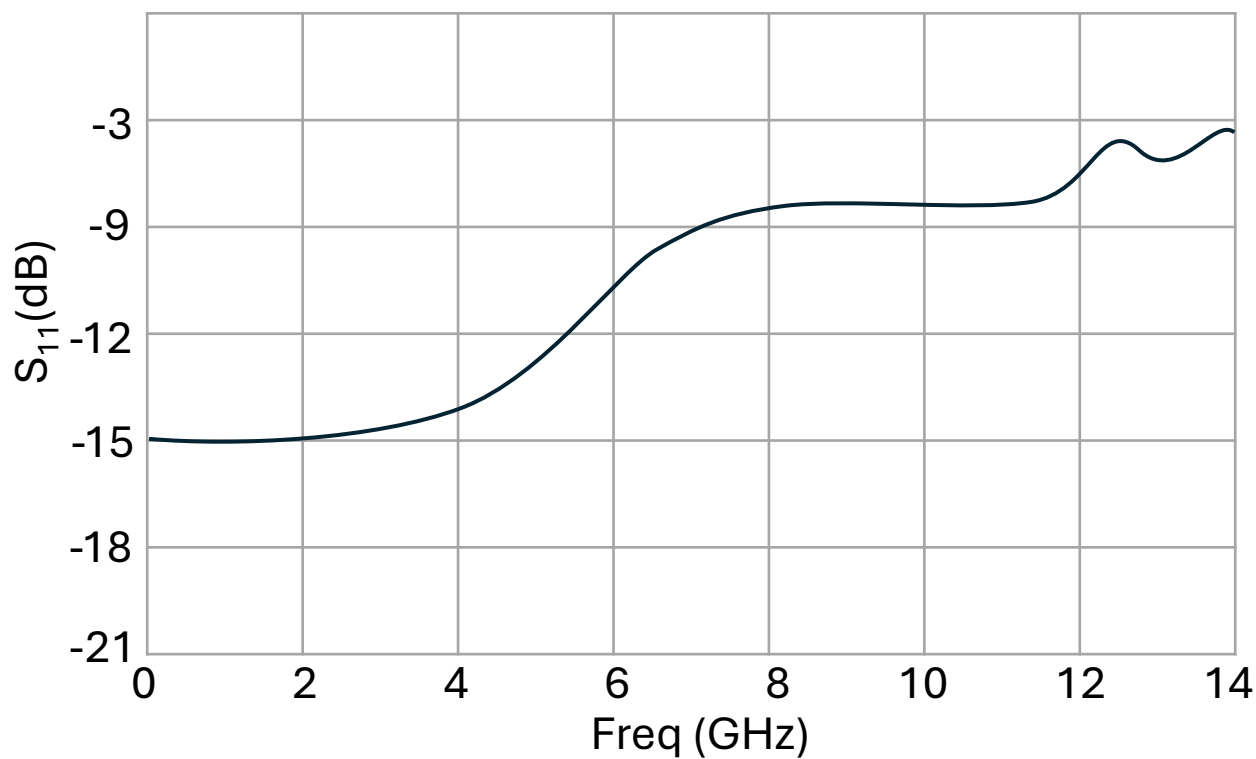
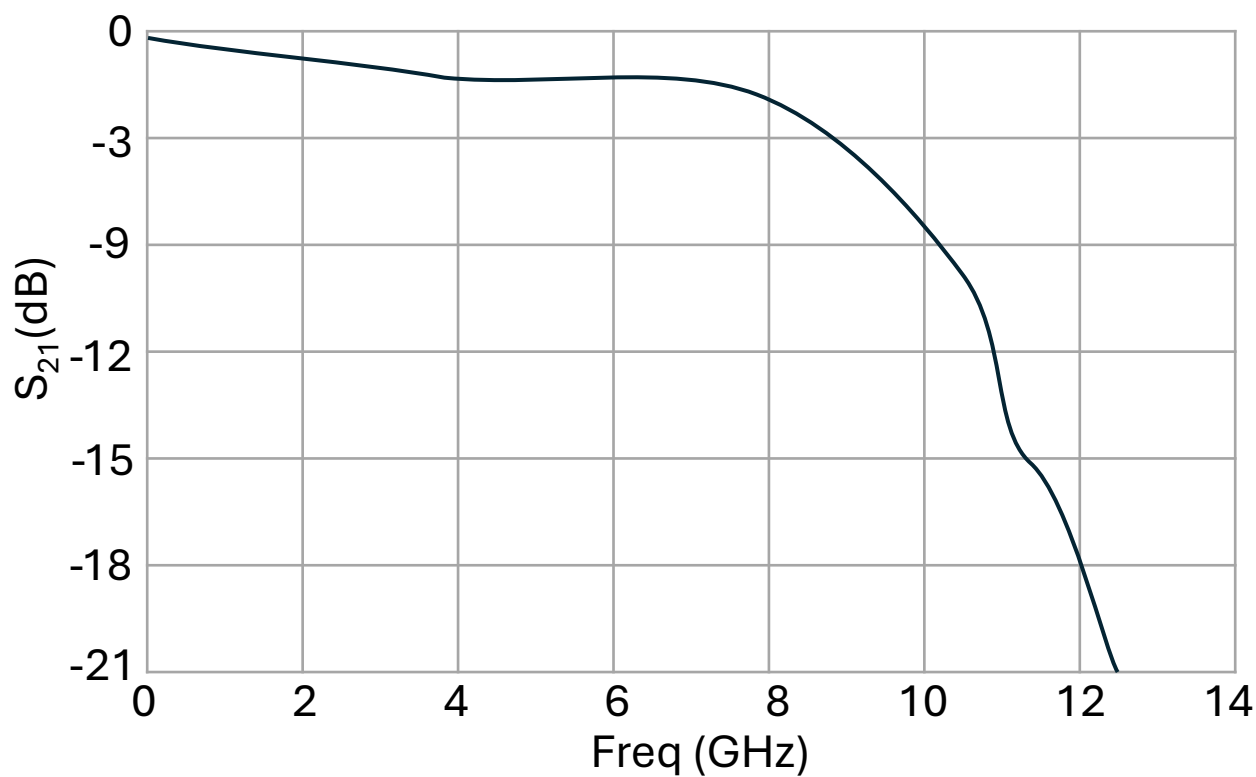
Parameter	Symbol	Condition	Min.	Max.	Unit
Voltage	V			3.6	V
V_{cc} current	I			40	mA
Input Optical Power	P_{in}			5	dBm
Storage Temperature	T_{stg}		-40	90	$^{\circ}\text{C}$
Storage Humidity	H_{stg}			85	% r.H.
Operating Temperature	T_{op}		-40	85	$^{\circ}\text{C}$
Soldering Temperature	T_{st}	10 sec		260	$^{\circ}\text{C}$
ESD Susceptibility		HBM	100		V

Operating at maximum operating specs for prolong periods of time will damage the device.

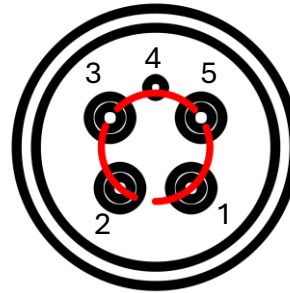
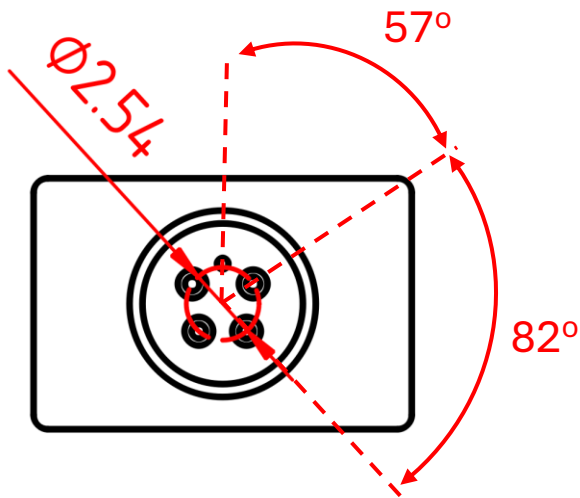


Typical Performance Curves (Top 23°C, 801 PTs, 16 AVGs, 1.5% smoothing)

RF performance dependent on PCB design and optimization. Data shown for Rogers® RO3003 with Ground-backed Co-planar waveguide (GB-CPW). The GB-CPW was de-embedded. Single ended measurement, port two is terminated with 50 Ohm load

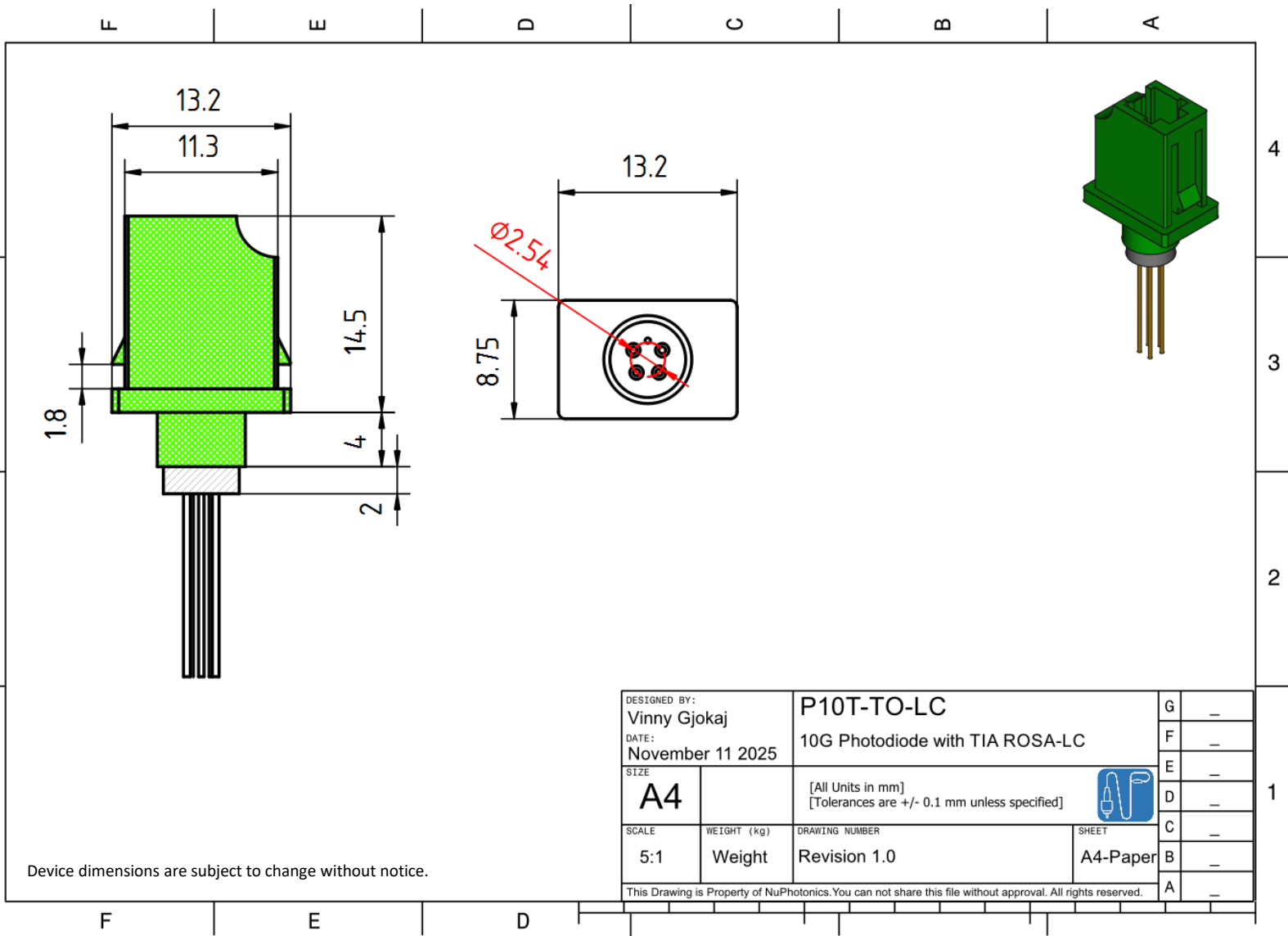


Device Pinout



Pin	Function
1	VCC
2	Imon
3	Dout -
4	Gnd
5	Dout +

Mechanical Drawing



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